
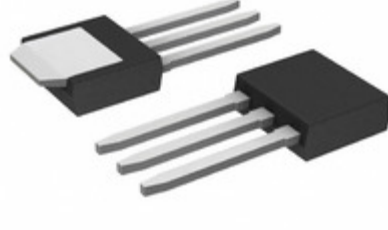
	<h2>NTD65N03R-001</h2>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">NTD65N03R-001</a></p> <p><b>Hersteller / Marke:</b> <a href="#">AMI Semiconductor / ON Semiconductor</a></p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 25V 9.5A IPAK</p> <p><b>Datenblätter:</b>  <a href="#">NTD65N03R-001.pdf</a></p> <p><b>RoHs Status:</b> Enthält Blei / RoHS nicht konform</p> <p><b>Lagerzustand:</b> New original, 6425 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	<a href="#">NTD65N03R-001</a>
Hersteller	<a href="#">AMI Semiconductor / ON Semiconductor</a>
Beschreibung	MOSFET N-CH 25V 9.5A IPAK
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	6425 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-251-3 Short Leads, IPak, TO-251AA
Supplier Device-Gehäuse	I-Pak
Verlustleistung (max)	1.3W (Ta), 50W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	25V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	9.5A (Ta), 32A (Tc)
Rds On (Max) @ Id, Vgs	8.4 mOhm @ 30A, 10V
VGS (th) (Max) @ Id	2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	16nC @ 5V
Eingabekapazität (Ciss) (Max) @ Vds	1400pF @ 20V
Verpackung	Tube



















































NTD65N03R-001 ist neu im Original, Suche NTD65N03R-001 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTD65N03R-001 AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTD65N03R-001: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>NTD65N03R-1G</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 9.5A IPAK</p>	 <p><b>NTD65N03R-35G VB</b> NTD65N03R-35G VB</p>	 <p><b>NTD65N03R-035</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 9.5A IPAK</p>	 <p><b>NTD65N03R</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 9.5A DPAK</p>
 <p><b>NTD6416ANLT4G</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 19A DPAK</p>	 <p><b>NTD6416ANL4G ON ON TO252</b></p>	 <p><b>NTD65N03RT4</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 9.5A DPAK</p>	 <p><b>NTD65N03G ON</b> NTD65N03G ON</p>

### heiße Teile

Mehr

 NTD60N02RG	 NTD60N02RG-1G	 NTD60N02RT	 NTD60N02RT4	 NTD60N02RT4G
 NTD60N03RT4G	 NTD60N03T4	 NTD60N03T4G	 NTD6414AN	 NTD6414AN-1G
 NTD6414ANT4G	 NTD6414AUG	 NTD6415AN	 NTD6415AN-1G	 NTD6415ANL
 NTD6415ANLT4G	 NTD6415ANT4G	 NTD6416AN	 NTD6416AN-1G	 NTD6416ANG
 NTD6416ANL	 NTD6416ANL-1G	 NTD6416ANLT4G	 NTD6416ANT4G	 NTD65N03G
 NTD65N03R-035	 NTD65N03R-1G	 NTD65N03R-35G	 NTD65N03RG	 NTD65N03RT4G
 NTD6600G	 NTD6600N	 NTD6600N-001	 NTD6600N-1G	 NTD6600NT4
 NTD6600NT4G	 NTD70N03	 NTD70N03R	 NTD70N03R-001	 NTD70N03R-1
 NTD70N03R-1G	 NTD70N03RG	 NTD70N03RT4	 NTD70N03RT4G	 NTD70N03TR4
 NTD78N03	 NTD78N03-001	 NTD78N03-035	 NTD78N03-1	 NTD78N03-1G

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

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